
150 mA 24 V Input High Voltage Regulator

NO.EA-270-200219

OUTLINE

The R1155x is a CMOS-based 24 V input voltage regulator featuring 150 mA output that provides high output voltage accuracy and low supply current. Internally, the R1155x consists of a voltage reference unit, an error amplifier, and a resistor net for setting output voltage. As protection circuits, the R1155x contains a current limit circuit, a fold-back protection circuit, a thermal shutdown circuit and a reverse current protection circuit.

The R1155x is available in the fixed output voltage type (R1155xxxxB), and the adjustable output voltage type (R1155x001C). The output voltage accuracy for the fixed output voltage type is as high as $\pm 2.0\%$.

The R1155x is offered in a 5-pin SOT-89-5 package and a 5-pin SOT-23-5 package.

FEATURES

- Supply Current Typ. 7.5 μA ($V_{\text{IN}} = 6.0 \text{ V}$ or 3.0 V)
- Standby Current Typ. 0.1 μA
- Output Current Min. 150 mA ($V_{\text{IN}} = 6.0 \text{ V}$ or 3.0 V)
- Output Voltage Accuracy $\pm 2.0\%$
- Package SOT-23-5, SOT-89-5
- Input Voltage Range Max. 24.0 V
- Output Voltage Range Fixed Output Voltage Type: 2.5 V to 12.0 V
Adjustable Output Voltage Type: 2.5 V, 2.5 V to 23.0 V
using external resistor
- Fold-back Protection Circuit Typ. 30 mA
- Thermal Shutdown Circuit
- Reverse Current Protection Circuit
- Ceramic Capacitor Capable $C_{\text{OUT}} = 4.7 \mu\text{F}$ or more

APPLICATIONS

- Power source for home appliances (refrigerators, rice cookers, electric water warmers, etc.)
- Power source for in-car audio systems, in-car navigation systems, ETC systems, and reset circuits
- Power source for laptop personal computers, digital TVs, cordless phones, and private LAN systems for home, and reset circuits
- Power source for copiers, printers, facsimiles, scanners, and reset circuits

R1155x

NO.EA-270-200219

SELECTION GUIDE

The output voltage, the output voltage type, and the package type for the ICs are user-selectable options.

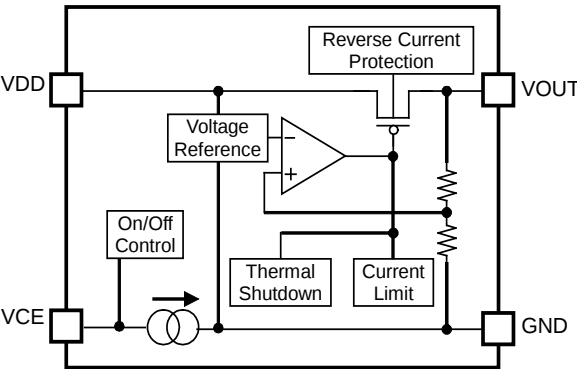
Selection Guide

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R1155Nxxx*-TR-FE	SOT-23-5	3,000 pcs	Yes	Yes
R1155Hxxx*-T1-FE	SOT-89-5	1,000 pcs	Yes	Yes

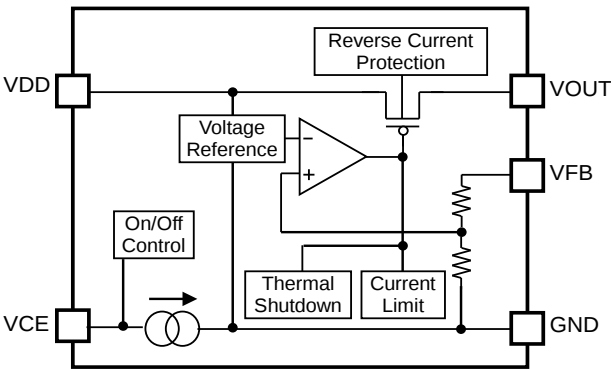
xxx: Designation of the output voltage (V_{SET})
For Fixed Output Voltage Type: 2.5 V (025) to 12 V (120) in 0.1 V steps
For Adjustable Output Voltage Type: 2.5 V (001) only

*: Designation of the output voltage type
(B) Fixed Output Voltage Type
(C) Adjustable Output Voltage Type

BLOCK DIAGRAMS

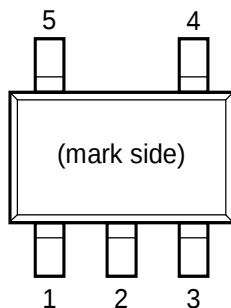


R1155xxxxB Block Diagram
(Fixed Output Voltage Type)

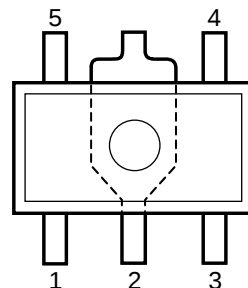


R1155x001C Block Diagram
(Adjustable Output Voltage Type)

PIN DESCRIPTION



SOT-23-5 Pin Configuration



SOT-89-5 Pin Configuration

SOT-23-5 Pin Description

Pin No	Symbol	Description	
1	VOUT	VR Output Pin	
2	GND	Ground Pin	
3	VDD	Input Pin	
4	TP ¹	R1155NxxxB	Test Pin
	VFB ²	R1155N001C ³	VR Adjustment Pin
5	CE	Chip Enable Pin, Active-high	

SOT-89-5 Pin Description

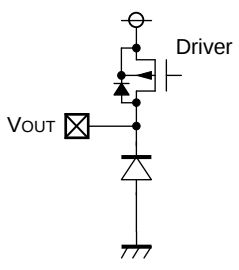
Pin No	Symbol	Description	
1	VOUT	VR Output Pin	
2	GND	Ground Pin	
3	CE	Chip Enable Pin, Active-high	
4	TP ¹	R1155HxxxB	Test Pin
	VFB ²	R1155H001C ³	VR Adjustment Pin
5	VDD	Input Pin	

¹ The TP pin must be connected to GND.

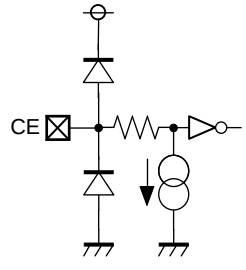
² A 24 KΩ or less voltage setting resistor must be connected to the VFB pin.

³ As for the adjustable output voltage type (R1155N001C), please refer to *ADJUSTABLE OUTPUT VOLTAGE TYPE SETTING*.

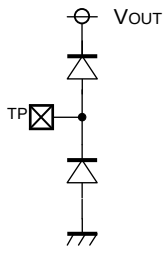
PIN EQUIVALENT CIRCUIT DIAGRAMS



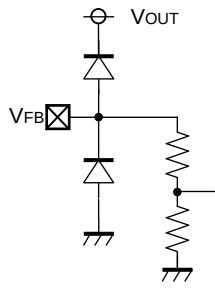
VOUT Pin Equivalent Circuit Diagram



VFB Pin Equivalent Circuit Diagram



TP Pin Equivalent Circuit Diagram
(R1155xxxxB)



VFB Pin Equivalent Circuit Diagram
(R1155x001C)

ABSOLUTE MAXIMUM RATINGS

Absolute Maximum Ratings

Symbol	Item	Rating	Unit
V_{IN}	Input Voltage	-0.3 to 26	V
V_{CE}	Input Voltage (CE Pin)	-0.3 to $V_{IN} + 0.3$	V
V_{OUT}	Output Voltage	-0.3 to 26	V
V_{VFB}	Output Voltage (VFB Pin)	-0.3 to 26	V
I_{OUT}	Output Current	350	mA
P_D	Power Dissipation	Refer to Appendix "Power Dissipation"	
T_j	Junction Temperature	-40 to 125	°C
T_{stg}	Storage Temperature Range	-55 to 125	°C

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause permanent damage and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

RECOMMENDED OPERATING CONDITIONS

Recommended Operating Ratings

Symbol	Item	Ratings	Unit
T_a	Operating Temperature Range	-40 to 105	°C
V_{IN}	Input Voltage	3.5 to 24	V

RECOMMENDED OPERATING RATINGS

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating ratings. The semiconductor devices cannot operate normally over the recommended operating ratings, even if they are used over such ratings by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating ratings.

R1155x

NO.EA-270-200219

ELECTRICAL CHARACTERISTICS

$V_{IN} = V_{CE} = V_{SET} + 3.0\text{ V}$, $C_{OUT} = 4.7\text{ }\mu\text{F}$, $I_{OUT} = 1\text{ mA}$, unless otherwise noted.

The specifications surrounded by are guaranteed by Design Engineering at $-40^{\circ}\text{C} \leq T_a \leq 105^{\circ}\text{C}$.

R1155xxxxB, R1155x001C Electrical Characteristics

($T_a = 25^{\circ}\text{C}$)

Symbol	Item	Conditions		Min.	Typ.	Max.	Unit
I_{LIM}	Output Current	$V_{IN} = V_{SET} + 4\text{ V}$		150			mA
V_{OUT}	Output Voltage (Low Power Mode)	$I_{OUT} = 1\text{ mA}$	$T_a = 25^{\circ}\text{C}$	$\times 0.98$		$\times 1.02$	V
			$-40^{\circ}\text{C} \leq T_a \leq 105^{\circ}\text{C}$	$\times 0.955$		$\times 1.03$	V
I_{SS1}	Supply Current (Low Power Mode)	$I_{OUT} = 0\text{ mA}$	$2.5 \leq V_{SET} \leq 4.2\text{ V}$		7.5	22	μA
			$4.2 < V_{SET} \leq 8.4\text{ V}$		8.6	22	μA
			$8.4 < V_{SET} \leq 12\text{ V}$		9.5	22	μA
I_{SS2}	Supply Current (Fast Mode)	$I_{OUT} = 10\text{ mA}$			65	125	μA
$I_{standby}$	Standby Current	$V_{IN} = 24\text{ V}$, $V_{CE} = 0\text{ V}$			0.1	1.0	μA
ΔV_{OUT}	Output Voltage Deviation When Switching Mode	$1\text{ mA} \leq I_{OUT} \leq 6\text{ mA}$		-1.5	0	1.5	%
$\frac{\Delta V_{OUT}}{\Delta I_{OUT}}$	Load Regulation (Fast Mode)	$6\text{ mA} \leq I_{OUT} \leq 150\text{ mA}$	$2.5 \leq V_{SET} \leq 5\text{ V}$		30	90	mV
			$5 < V_{SET} \leq 12\text{ V}$		30	100	mV
$\frac{\Delta V_{OUT}}{\Delta V_{IN}}$	Line Regulation (Low Power Mode)	$V_{SET} + 0.2\text{ V} \leq V_{IN} \leq 24\text{ V}$	$I_{OUT} = 1\text{ mA}$		0.3	1.3	%
	Line Regulation (Fast Mode)	$V_{SET} + 0.2\text{ V} \leq V_{IN} \leq 24\text{ V}$	$I_{OUT} = 10\text{ mA}$		1.2	2.4	%
V_{DIF}	Dropout Voltage	$I_{OUT} = 150\text{ mA}$	$2.5\text{ V} \leq V_{SET} < 3.3\text{ V}$		1.6	2.6	V
			$3.3\text{ V} \leq V_{SET} < 5\text{ V}$		0.96	2.1	V
			$5 \leq V_{SET} \leq 12\text{ V}$		0.55	1.7	V
RR	Ripple Rejection (Fast Mode)	$f = 1\text{ kHz}$, 0.5 V_{p-p} , $I_{OUT} = 10\text{ mA}$	$2.5 \leq V_{SET} < 5\text{ V}$		60		dB
			$5 \leq V_{SET} \leq 12\text{ V}$		50		dB
$\frac{\Delta V_{OUT}}{\Delta T_a}$	Output Voltage Temperature Coefficient	$I_{OUT} = 1\text{ mA}$, $-40^{\circ}\text{C} \leq T_a \leq 105^{\circ}\text{C}$			± 100		ppm/ $^{\circ}\text{C}$
I_{OUTH}	Fast Mode Switching Current	$I_{OUT} = \text{Light Load} \rightarrow \text{Heavy Load}$		2.4	4.5	6.5	mA
I_{OUTL}	Low Power Mode Switching Current	$I_{OUT} = \text{Heavy Load} \rightarrow \text{Light Load}$		0.6	1.5	2.4	mA
I_{SC}	Short Current Limit	$V_{OUT} = 0\text{ V}$			30		mA
V_{CEH}	CE Input Voltage "H"			1.35		V_{IN}	V
V_{CEL}	CE Input Voltage "L"			0		0.5	V
T_{TSD}	Thermal Shutdown Temperature	Junction Temperature			145		$^{\circ}\text{C}$
T_{TSR}	Thermal Shutdown Released Temperature	Junction Temperature			120		$^{\circ}\text{C}$

All test items listed under *ELECTRICAL CHARACTERISTICS* are done under the pulse load condition ($T_j \approx T_a = 25^{\circ}\text{C}$) except for Ripple Rejection and Output Voltage Temperature Coefficient.

ELECTRICAL CHARACTERISTICS (continued)

$V_{IN} = V_{CE} = V_{SET} + 3.0\text{ V}$, $C_{OUT} = 4.7\text{ }\mu\text{F}$, $I_{OUT} = 1\text{ mA}$, unless otherwise noted.

The specifications surrounded by are guaranteed by Design Engineering at $-40^{\circ}\text{C} \leq T_a \leq 105^{\circ}\text{C}$.

R1155xxxxB, R1155x001C Electrical Characteristics

(Ta = 25°C)

Symbol	Item	Conditions		Min.	Typ.	Max.	Unit
I_{REV}	Reverse Current Limit	CE = GND, $V_{IN} = V_{SET} + 0.02\text{ V}$	$2.5 \leq V_{SET} < 5\text{ V}$		1.0	3.5	μA
			$5 \leq V_{SET} \leq 12\text{ V}$		2.0	6.0	μA
V_{REV_DET}	Reverse Current Protection Mode Detection Offset ¹ $V_{REV} = V_{DD} - V_{OUT}$	$0 \leq V_{IN} \leq 24.0\text{ V}$, $V_{OUT} \geq 2.0\text{ V}$		20			mV
V_{REV_REL}	Reverse Current Protection Mode Release Offset ¹	$0 \leq V_{IN} \leq 24.0\text{ V}$, $V_{OUT} \geq 2.0\text{ V}$				220	mV

All test items listed under *ELECTRICAL CHARACTERISTICS* are done under the pulse load condition ($T_j \approx T_a = 25^{\circ}\text{C}$) except for Ripple Rejection and Output Voltage Temperature Coefficient.

¹ The operation of reverse current protection circuit is guaranteed when $V_{OUT} \geq 2.0\text{ V}$. The reverse current protection mode is always turned on when $V_{IN} = 0\text{ V}$.

THEORY OF OPERATION

Power Activation

When starting up the IC using the input voltages of the VDD and CE pins simultaneously with no load, the both pin voltages have to be 0.06 V/ ms or faster. When starting up the IC using the both pin voltages at 0.06 V/ ms or slower with no load, the VDD pin has to be started up before the CE pin.

Thermal Shutdown Circuit

The R1155x contains a thermal shutdown circuit, which stops regulator operation if the junction temperature of the R1155x becomes higher than 145°C (Typ.). Additionally, if the junction temperature after the regulator being stopped decreases to a level below 120°C (Typ.), it restarts regulator operation. As a result the operation of the thermal shutdown circuit causes the regulator repeatedly to turn off and on until the causes of overheating are removed. As a consequence a pulse shaped output voltage occurs.

Reverse Current Protection Circuit

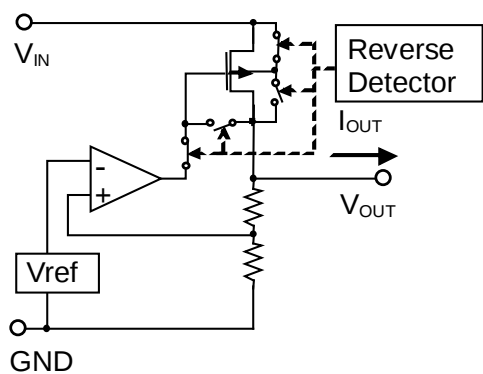
The R1155x includes a reverse current protection circuit, which stops the reverse current flowing from the VOUT to VDD pins or to GND pin when V_{OUT} becomes more than V_{IN} .

Usually, the LDO using Pch output transistor contains a parasitic diode between VDD pin and VOUT pin. Therefore, if V_{OUT} is more than V_{IN} , the parasitic diode becomes forward direction. As a result, the current flows from VOUT pin to VDD pin.

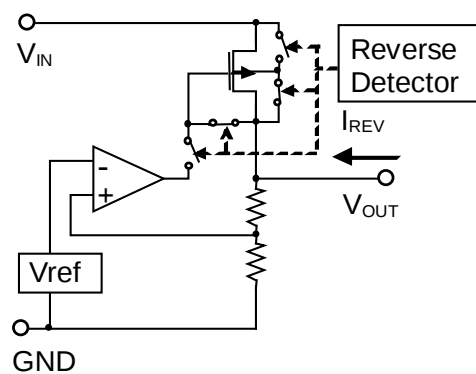
The R1155x switches the mode to the reverse current protection mode before V_{IN} becomes smaller than V_{OUT} by connecting the parasitic diode of Pch output transistor to the backward direction, and connecting the gate to VOUT pin. As a result, the Pch output transistor is turned off and the all the current pathways from VOUT pin to GND pin are shut down to maintain the reverse current lower than $[I_{REV}]$ of the Electrical Characteristics. Switching to either the normal mode or to the reverse current protection mode is determined by the magnitude of V_{IN} voltage and V_{OUT} voltage. For the stable operation, offset and hysteresis are set as the threshold. The detection/ release thresholds of both normal and reverse current protection modes are specified by $[V_{REV_DET}]$ and $[V_{REV_REL}]$ of the Electrical Characteristics. Therefore, the minimum dropout voltage under the small load current condition is restricted by the value of $[V_{REV_REL}]$.

Figure 7 and Figure 8 show the normal operation mode and reverse current protection mode, respectively. Figure 9 shows the detection/ release timing of reverse current protection function. When giving the VOUT pin a constant-voltage and decreasing the V_{IN} voltage, the dropout voltage will become lower than the $[V_{REV_DET}]$. As a result, the reverse current protection starts to function to stop the load current. By increasing the dropout voltage more than the $[V_{REV_REL}]$, the protection mode will be released to let the load current to flow. If the dropout voltage to be used is smaller than $[V_{REV_REL}]$, the detection and the release may be repeated.

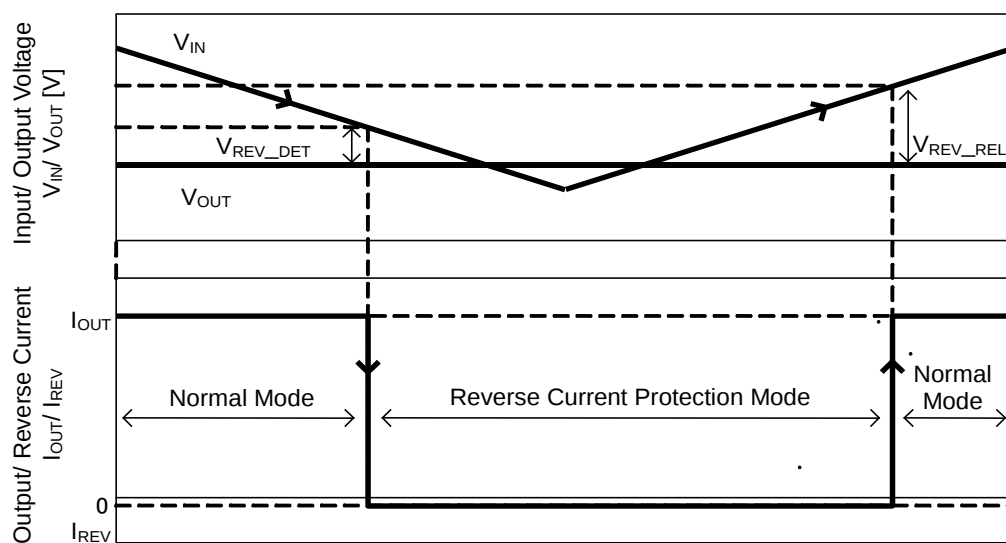
The operation coverage of the reverse current protection circuit is $V_{OUT} \geq 1.5$ V. However, under the condition of $V_{IN} = 0$ V, always the reverse current protection mode is operating.



Normal Operation Mode

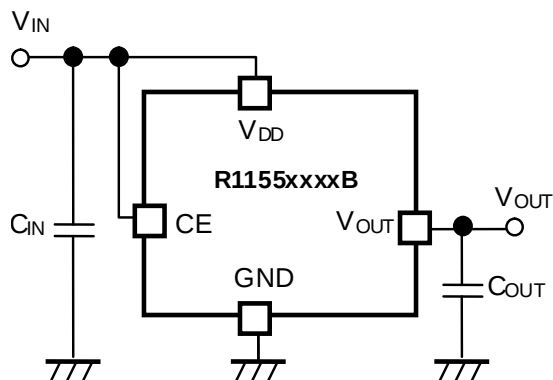


Reverse Current Protection Mode

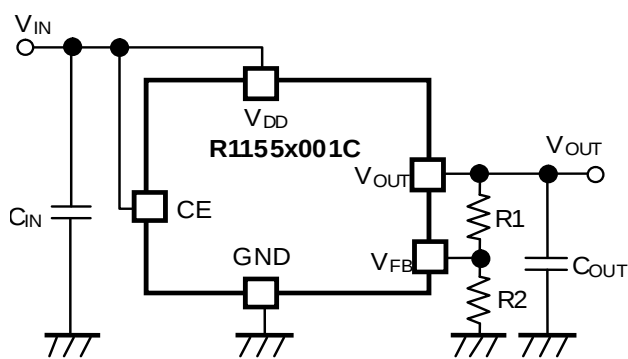


Detection/ Release Timing of Reverse Current Protection Function

APPLICATION INFORMATION



R1155xxxxB Typical Application
(Fixed Output Voltage Type)



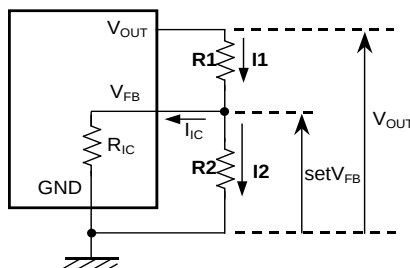
R1155x001C Typical Application
(Adjustable Output Voltage Type)

Technical Notes on the Components Selection

- In the R1155x, phase compensation is provided to secure stable operation even when the load current is varied. For this purpose, use a 4.7 μF or more output capacitor (C_{OUT}) with good frequency characteristics and proper ESR (Equivalent Series Resistance). In case of using a tantalum type capacitor and the ESR value of the capacitor is large, the output might be unstable. Evaluate the circuit including consideration of frequency characteristics.
- Ensure the VDD and GND lines are sufficiently robust. If their impedance is too high, noise pickup or unstable operation may result. Connect C_{OUT} with suitable values between the VOUT and GND pins, and as close as possible to the pins. Please refer to Figure 5 and Figure 6 below.

Adjustable Output Voltage Type Setting (R1155x001C)

The output voltage of the R1155x001C can be adjusted up to 23 V by using the external divider resistors (R1, R2). The resistance value for R2 should be set to 24 K Ω or less. By using the following equations, the output voltage can be determined. V_{FB} voltage which is fixed inside the IC is described as $setV_{FB}$. $setV_{FB}$ is 2.5 V. When using the R1155x001C with 2.5 V, please connect the VOUT pin to the VFB pin.



Output Voltage Adjustment Using External Divider Resistors

$$I1 = I_{IC} + I2 \dots\dots\dots (1)$$

$$I2 = setV_{FB} / R2 \dots\dots\dots (2)$$

Thus,

$$I1 = I_{IC} + setV_{FB} / R2 \dots\dots\dots (3)$$

Therefore,

$$V_{OUT} = setV_{FB} + R1 \times I1 \dots\dots\dots (4)$$

Insert Equation (3) into Equation (4), so

$$\begin{aligned} V_{OUT} &= setV_{FB} + R1 \times (I_{IC} + setV_{FB} / R2) \\ &= setV_{FB} \times (1 + R1 / R2) + R1 \times I_{IC} \dots\dots\dots (5) \end{aligned}$$

In Equation (5), $R1 \times I_{IC}$ is the error-causing factor in V_{OUT} .

As for I_{IC} ,

$$I_{IC} = setV_{FB} / R_{IC} \dots\dots\dots (6)$$

Therefore, the error-causing factor $R1 \times I_{IC}$ can be described as follows.

$$\begin{aligned} R1 \times I_{IC} &= R1 \times setV_{FB} / R_{IC} \\ &= setV_{FB} \times R1 / R_{IC} \dots\dots\dots (7) \end{aligned}$$

For better accuracy, choosing $R1 \ll R_{IC}$ reduces this error.

Without the error-causing factor $R1 \times I_{IC}$, the output voltage can be calculated by the following equation.

$$V_{OUT} = setV_{FB} \times ((R1 + R2) / R2) \dots\dots\dots (8)$$

R_{IC} of the R1155x001C is approximately Typ.8.4 M Ω ($T_a = 25^\circ\text{C}$, guaranteed by Design Engineering).

R_{IC} could be affected by the temperature, therefore evaluate the circuit taking the actual conditions of use into account when deciding the resistance values for R1 and R2.

R1155x

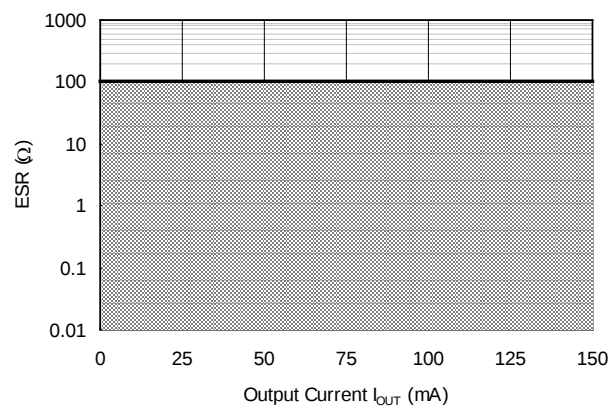
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Equivalent Series Resistance (ESR) vs. Output Current (I_{OUT})

It is recommended that a ceramic type capacitor be used for the R1155x. However, other types of capacitors having lower ESR can also be used. The relation between the output current (I_{OUT}) and the ESR of output capacitor is shown below.

Measurement Conditions:

- Noise Frequency Band: 10 Hz to 2 MHz
- Measurement Temperature: -40°C to $+105^{\circ}\text{C}$
- Hatched Area: Noise level is 40 μV (avg.) or below.
- C_{IN} : 0.1 μF
- C_{OUT} : 4.7 μF

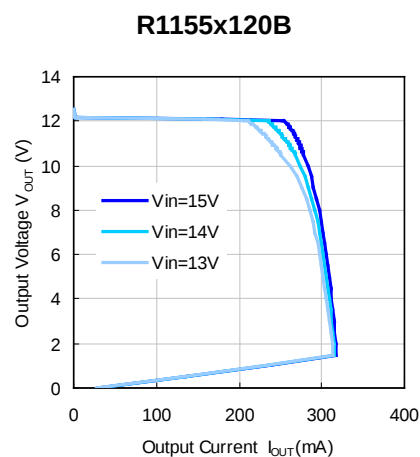
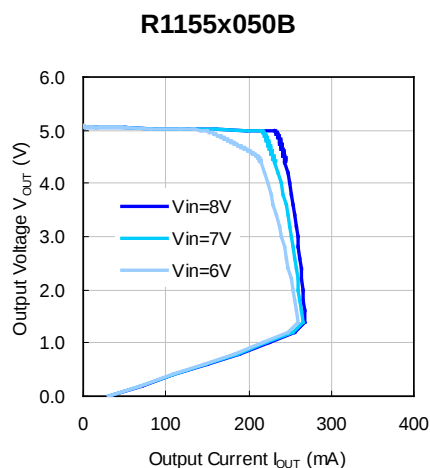
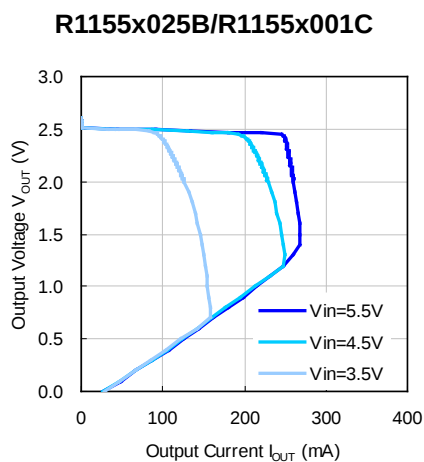


ESR vs. Output Current

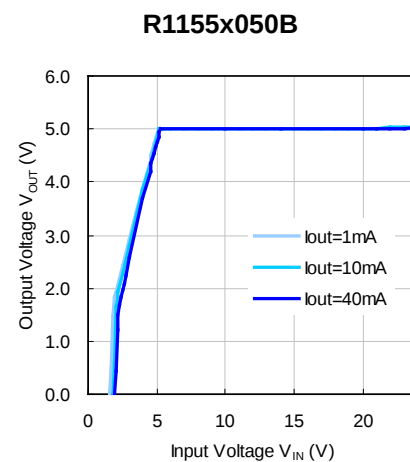
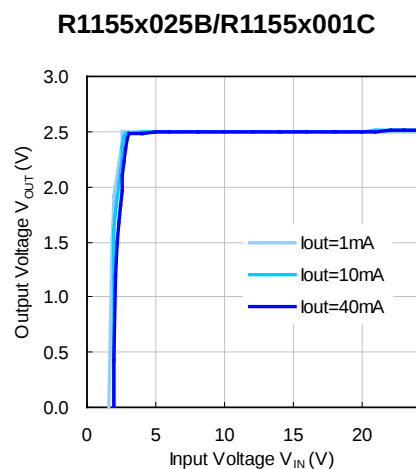
TYPICAL CHARACTERISTICS

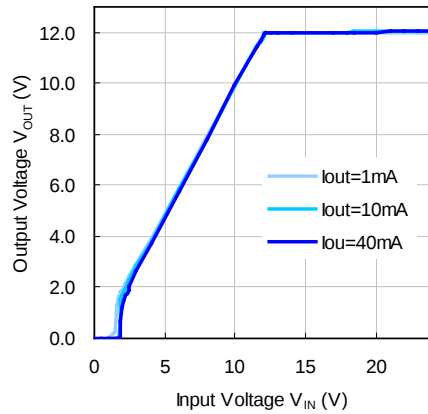
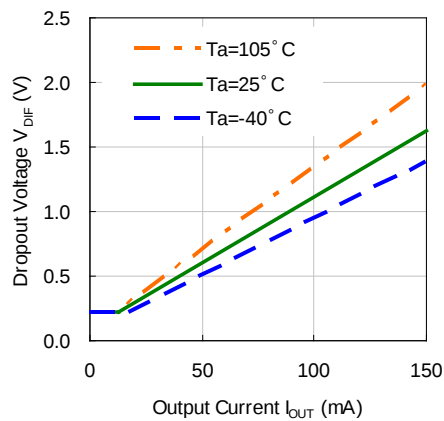
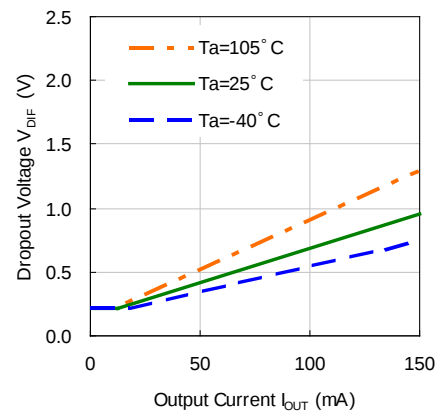
Note: Typical Characteristics are intended to be used as reference data; they are not guaranteed.

1) Output Voltage vs. Output Current ($C_{IN} = 0.1 \mu F$, $C_{OUT} = 4.7 \mu F$, $T_a = 25^\circ C$)

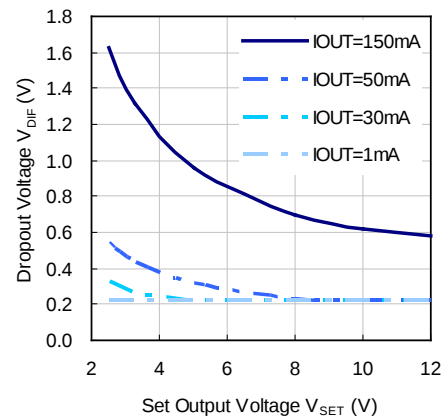
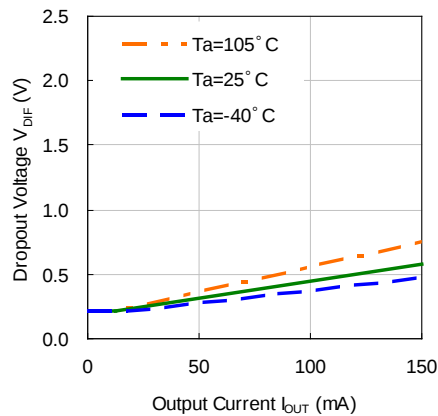


2) Output Voltage vs. Input Voltage ($C_{IN} = 0.1 \mu F$, $C_{OUT} = 4.7 \mu F$, $T_a = 25^\circ C$)



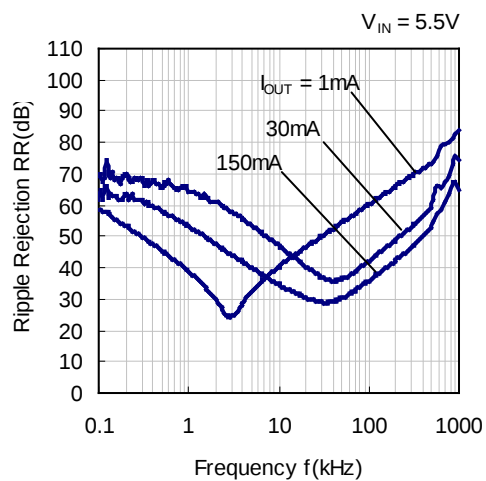
R1155x120B

3) Dropout Voltage vs. Output Current ($C_{IN} = 0.1 \mu\text{F}$, $C_{OUT} = 4.7 \mu\text{F}$)
R1155x025B/R1155x001C

R1155x050B

4) Dropout Voltage vs. Set Output Voltage

 ($C_{IN} = 0.1 \mu\text{F}$, $C_{OUT} = 4.7 \mu\text{F}$, $T_a = 25^\circ\text{C}$)

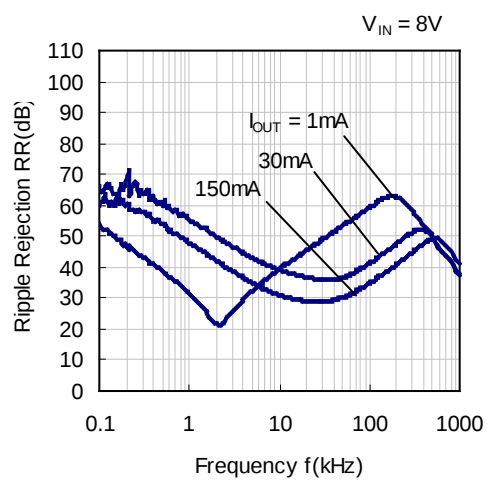
R1155x120B


5) Ripple Rejection vs. Frequency (C_{IN} = none, C_{OUT} = 4.7 μ F, Ripple = 0.2 V_{P-P}, T_a = 25°C)

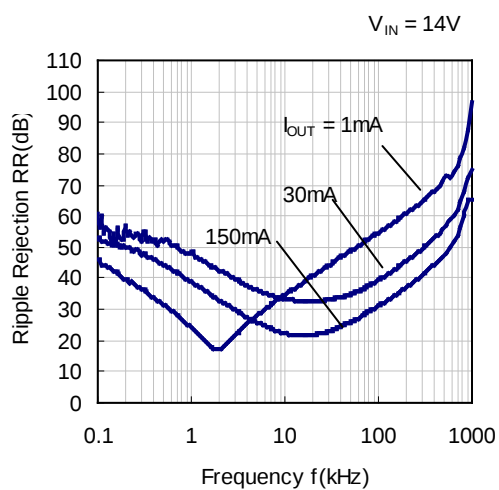
R1155x025B



R1155x050B



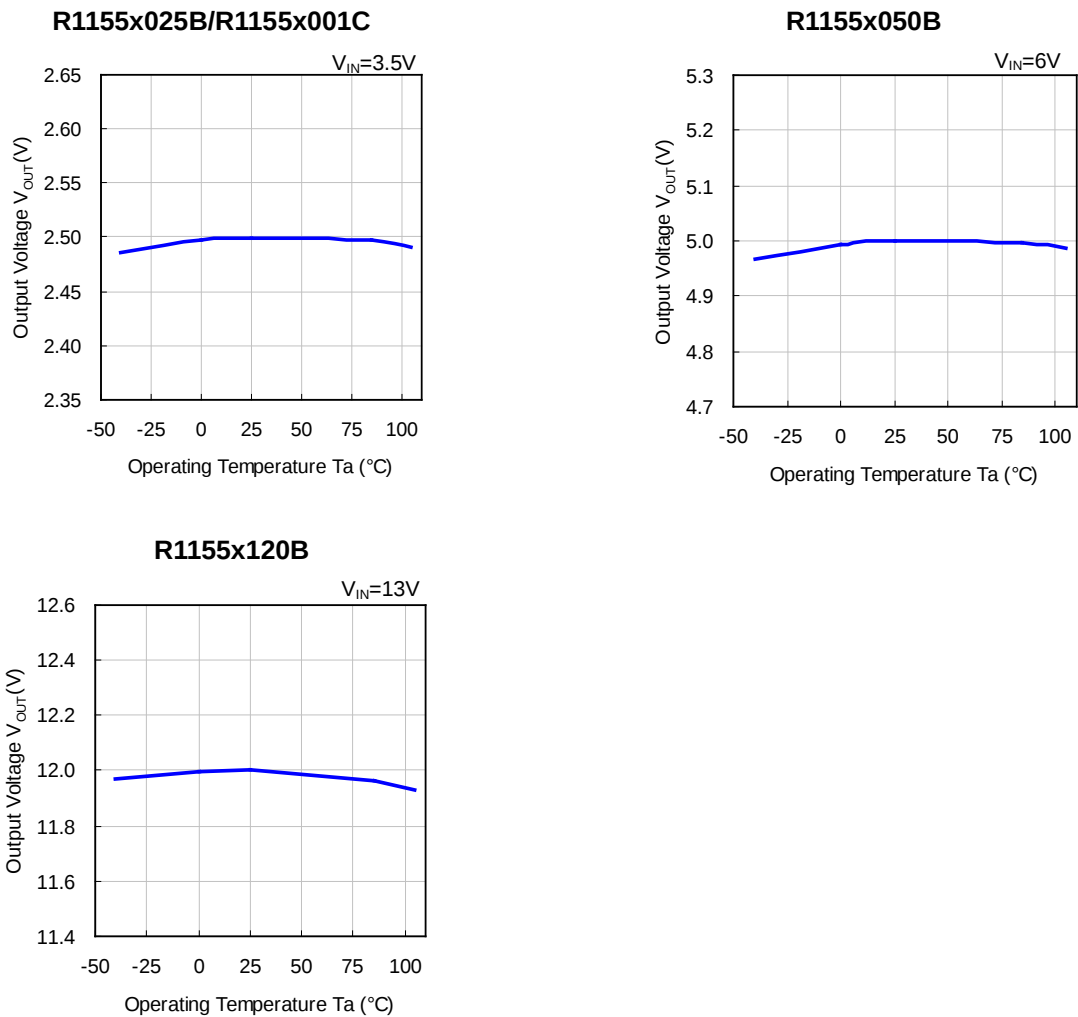
R1155x120B



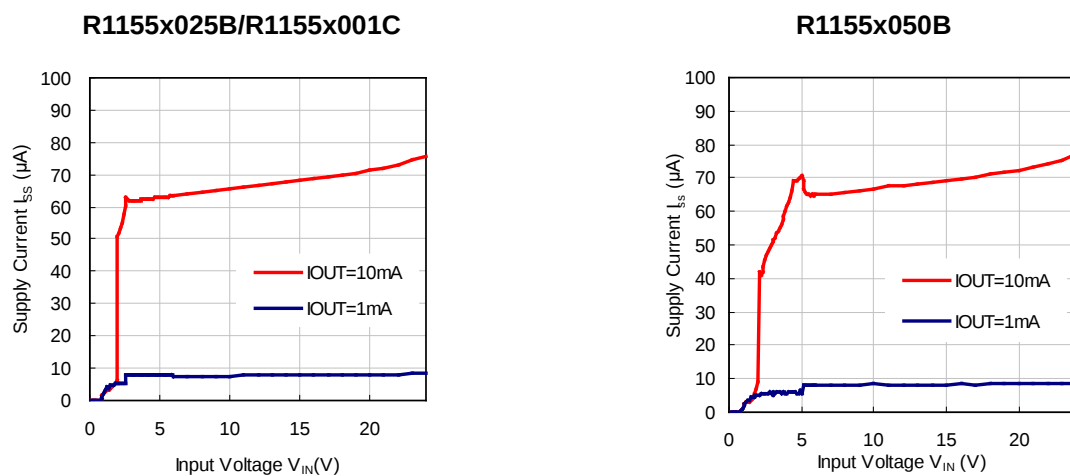
R1155x

NO.EA-270-200219

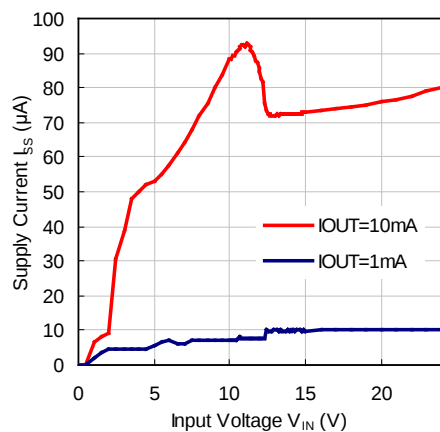
6) Output Voltage vs. Operating Temperature ($C_{IN} = 0.1 \mu F$, $C_{OUT} = 4.7 \mu F$, $T_a = 25^\circ C$, $I_{OUT} = 1 \text{ mA}$)



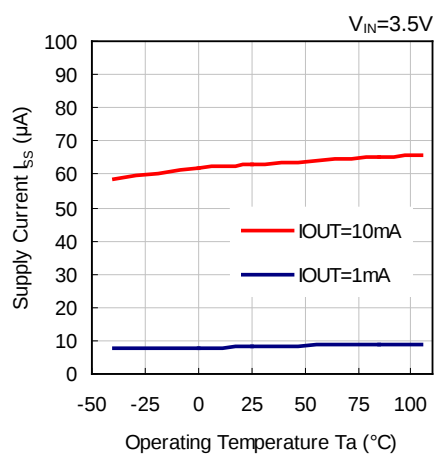
7) Supply Current vs. Input Voltage ($C_{IN} = 0.1 \mu F$, $C_{OUT} = 4.7 \mu F$, $T_a = 25^\circ C$)



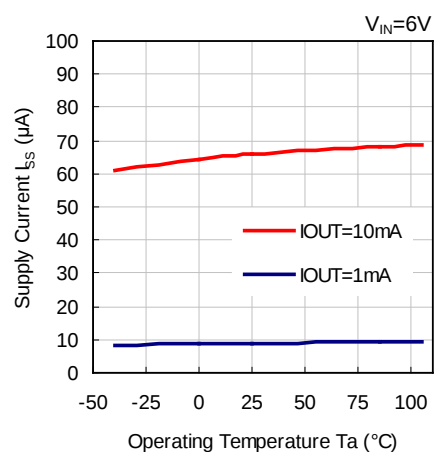
R1155x120B

8) Supply Current vs. Operating Temperature ($C_{IN} = 0.1 \mu F$, $C_{OUT} = 4.7 \mu F$)

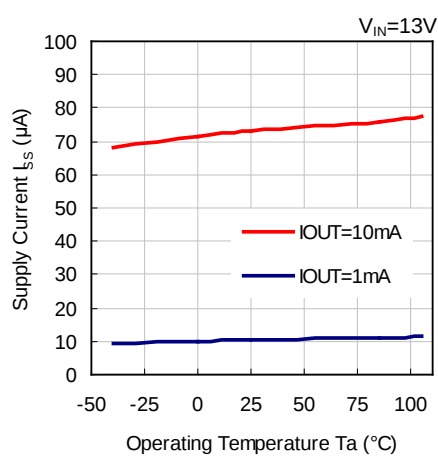
R1155x025B/R1155x001C



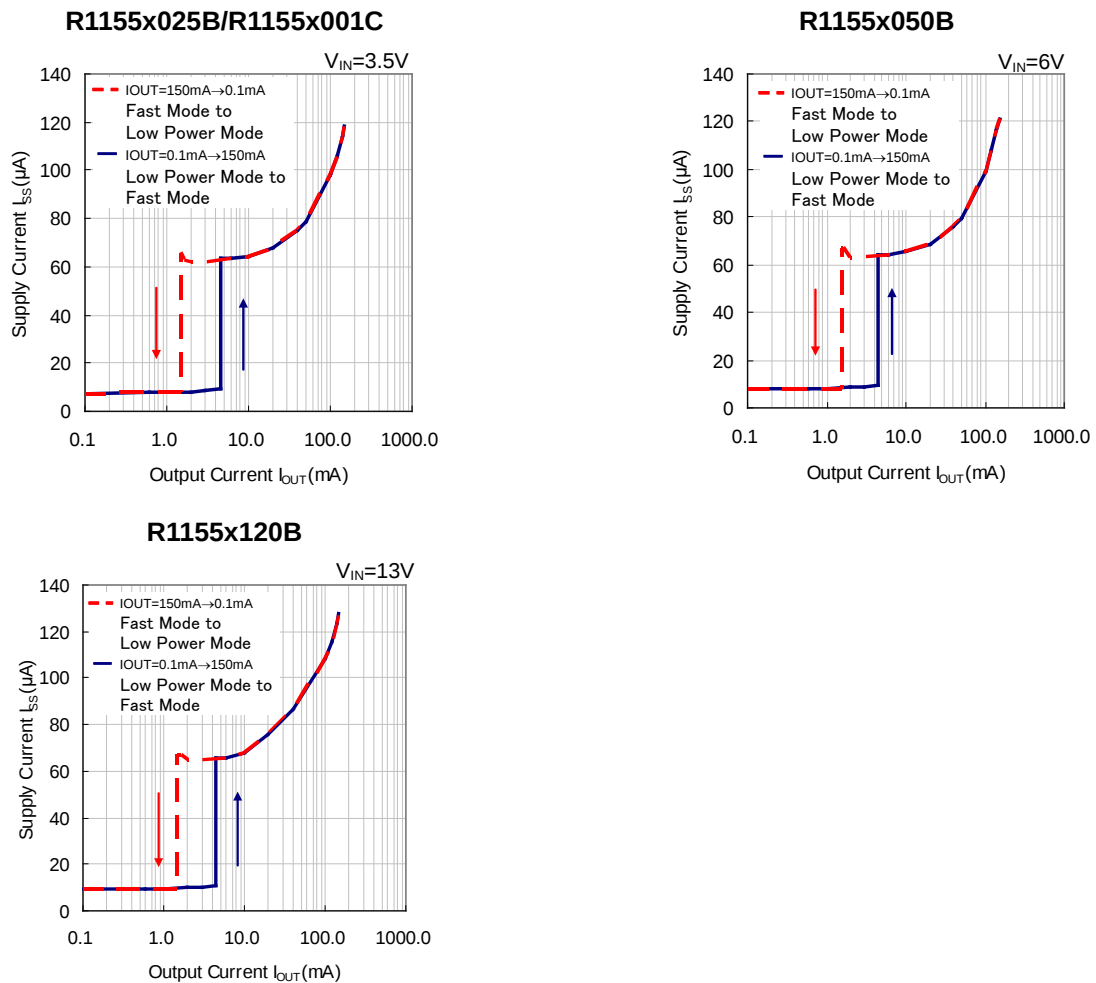
R1155x050B



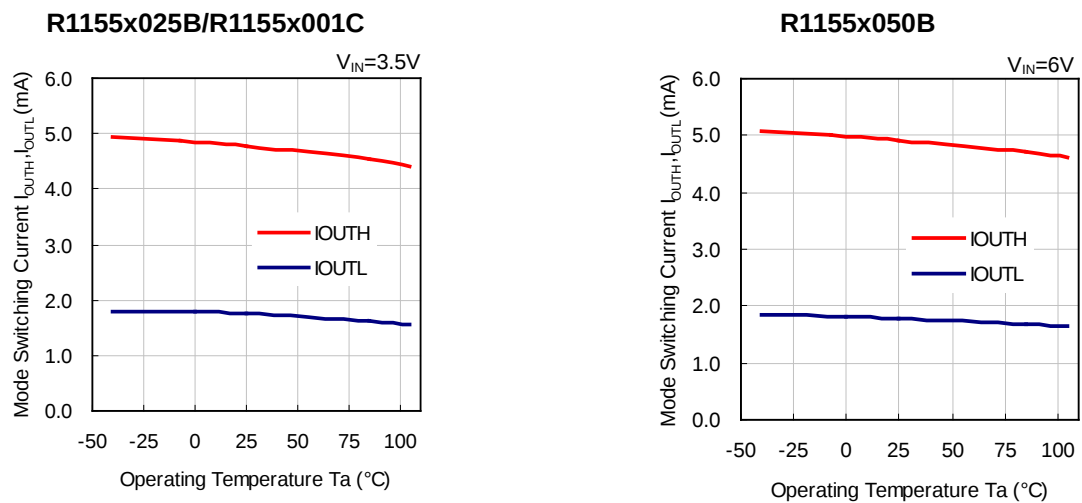
R1155x120B

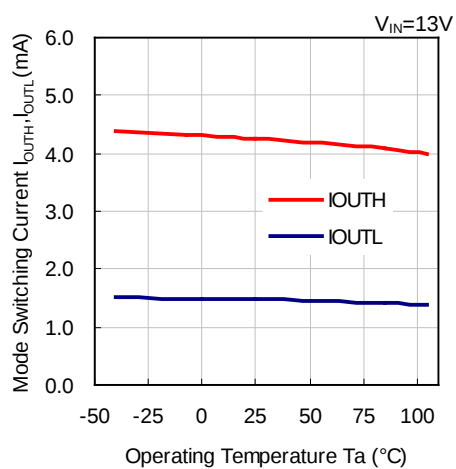
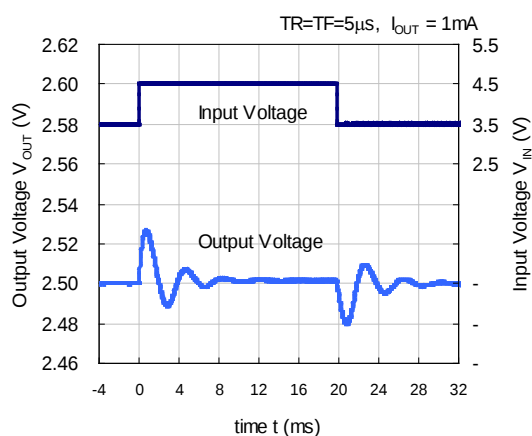
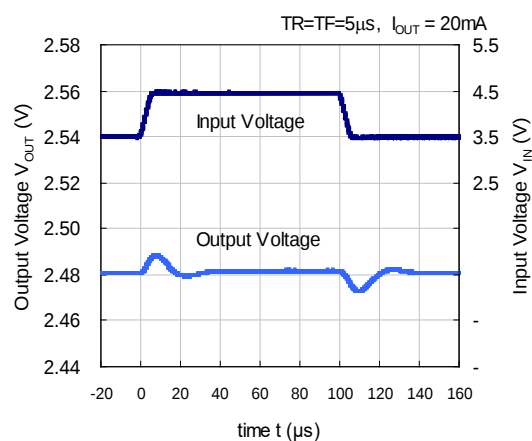
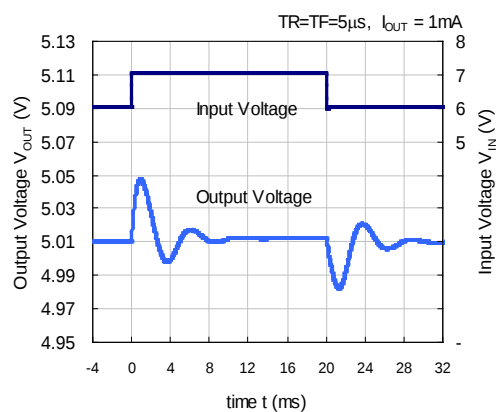
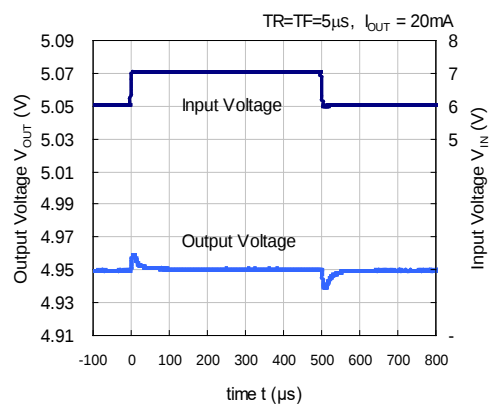


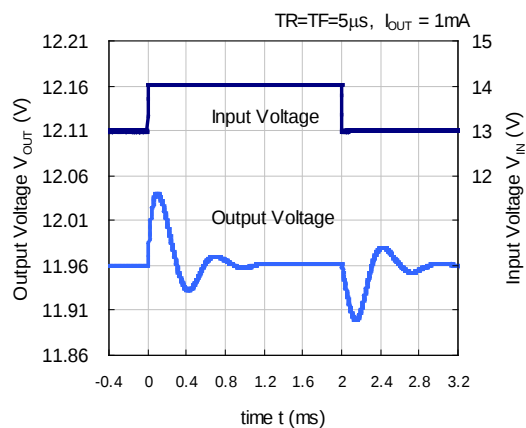
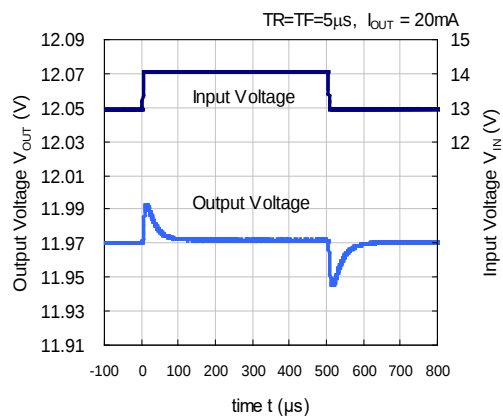
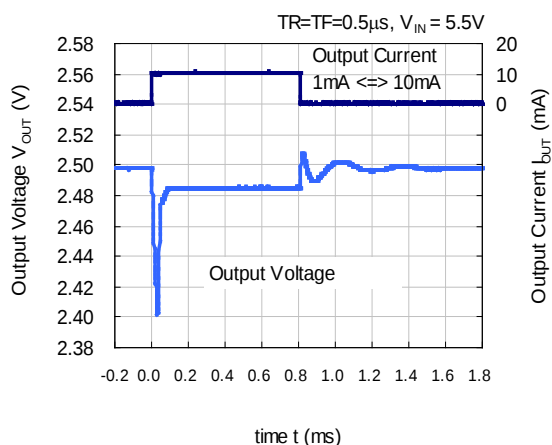
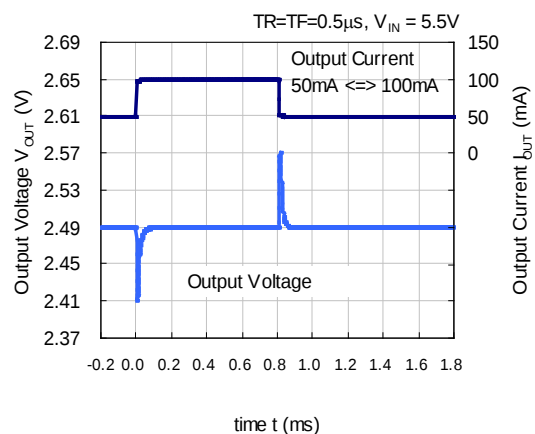
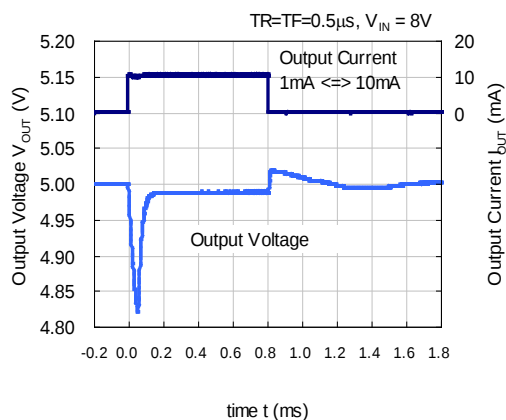
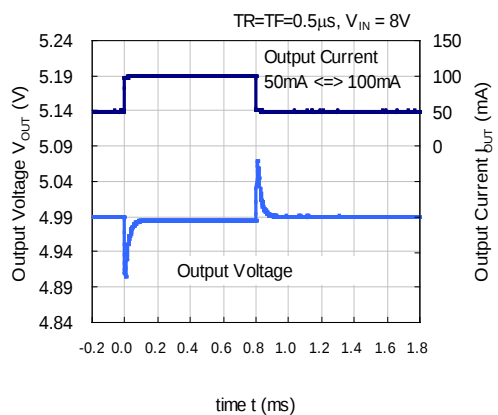
9) Supply Current vs. Output Current ($C_{IN} = 0.1 \mu F$, $C_{OUT} = 4.7 \mu F$, $T_a = 25^\circ C$)



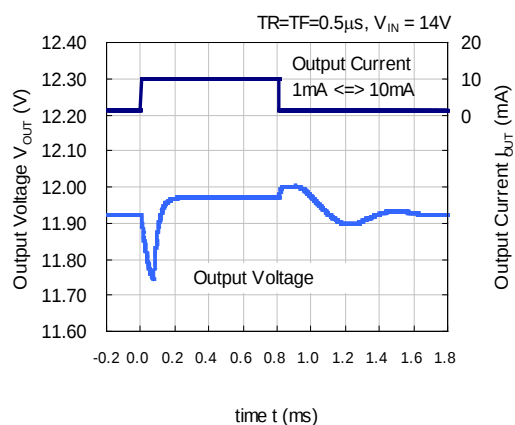
10) Mode Switching Current vs. Operating Temperature ($C_{IN} = 0.1 \mu F$, $C_{OUT} = 4.7 \mu F$)



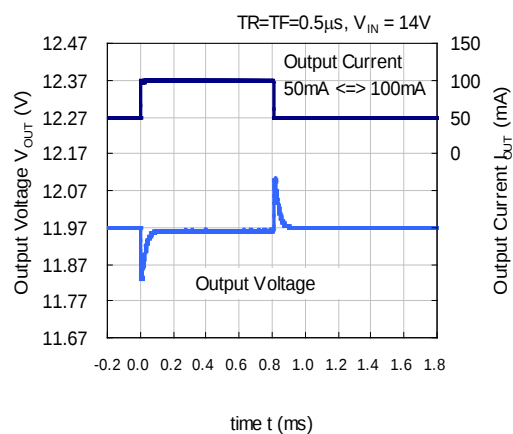
R1155x120B**11) Input Transient Response ($C_{OUT} = 4.7 \mu F$, $T_a = 25^\circ C$)****R1155x025B****R1155x025B****R1155x050B****R1155x050B**

R1155x120B

R1155x120B

12) Load Transient Response ($C_{OUT} = 4.7\text{ }\mu\text{F}$, $T_a = 25^\circ\text{C}$)
R1155x025B

R1155x025B

R1155x050B

R1155x050B


R1155x120B

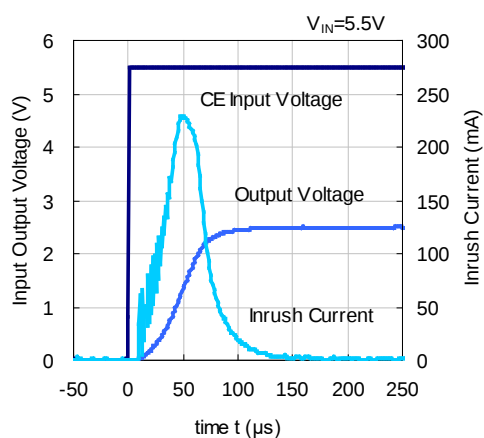


R1155x120B

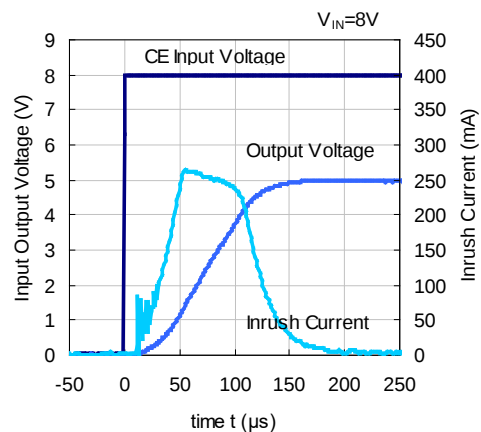


13) CE Input Voltage vs. Output Voltage vs. Inrush Current (C_{IN} = 0.1 μ F, C_{OUT} = 4.7 μ F, T_a = 25°C)

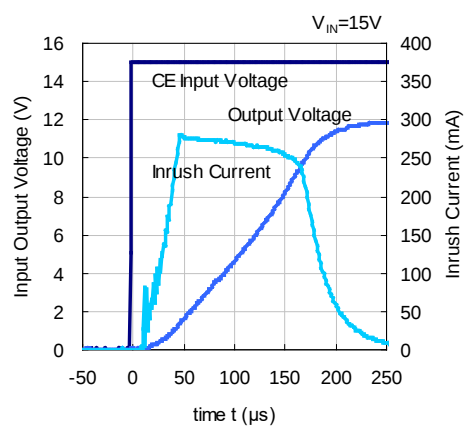
R1155x025B



R1155x050B



R1155x120B



The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

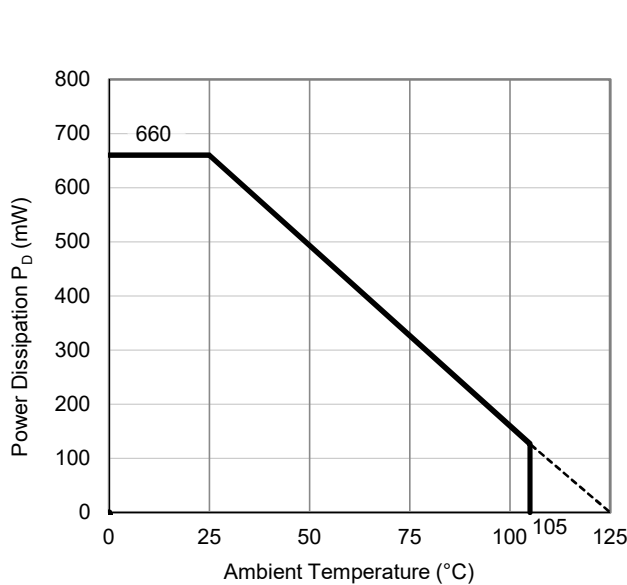
Measurement Conditions

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.3 mm × 7 pcs

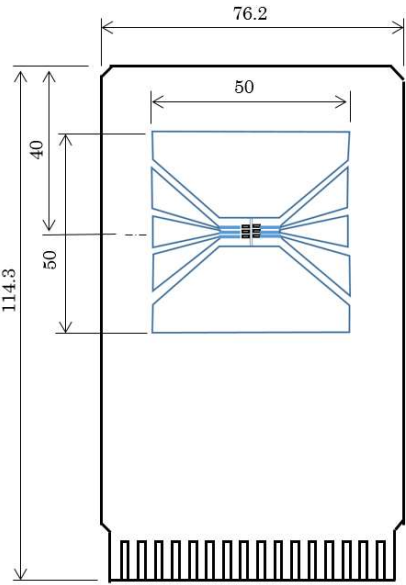
Measurement Result (Ta = 25°C, Tjmax = 125°C)

Item	Measurement Result
Power Dissipation	660 mW
Thermal Resistance (θja)	θja = 150°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 51°C/W

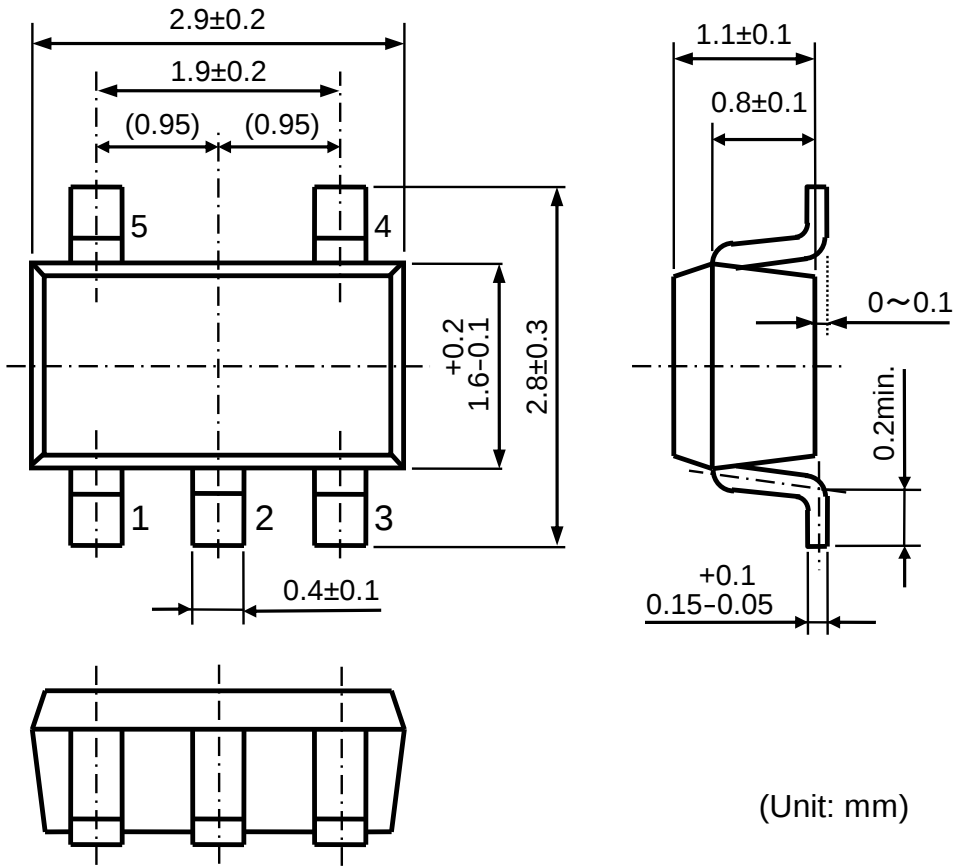
θja: Junction-to-Ambient Thermal Resistance
ψjt: Junction-to-Top Thermal Characterization Parameter



Power Dissipation vs. Ambient Temperature



Measurement Board Pattern



SOT-23-5 Package Dimensions

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

Measurement Conditions

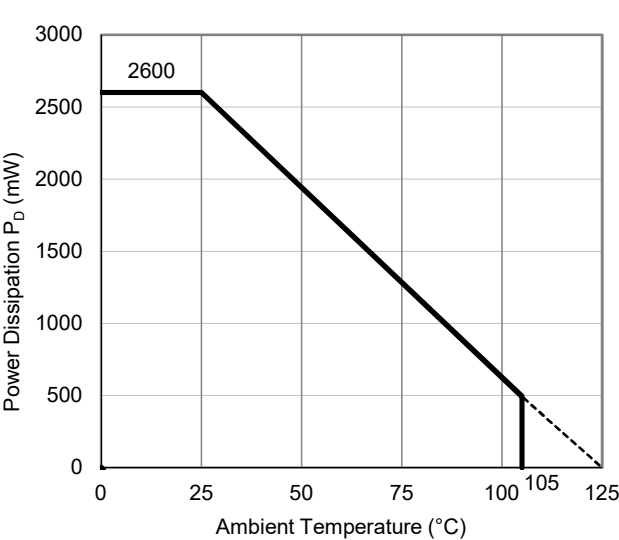
Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.3 mm × 13 pcs

Measurement Result

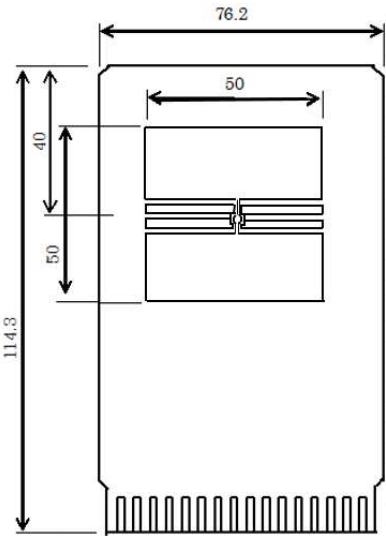
(Ta = 25°C, Tjmax = 125°C)

Item	Measurement Result
Power Dissipation	2600 mW
Thermal Resistance (θja)	θja = 38°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 13°C/W

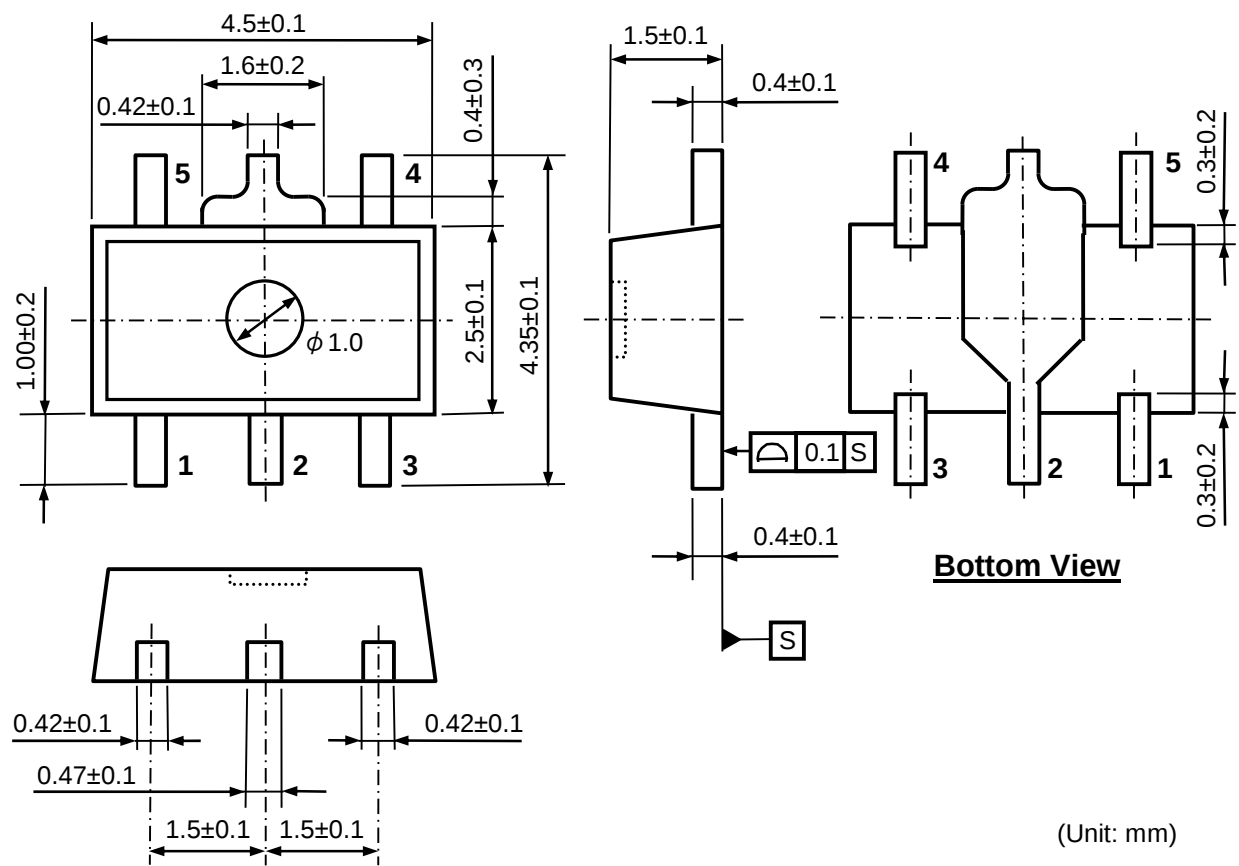
θja: Junction-to-Ambient Thermal Resistance
ψjt: Junction-to-Top Thermal Characterization Parameter



Power Dissipation vs. Ambient Temperature



Measurement Board Pattern



SOT-89-5 Package Dimensions



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